



Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C		
60)/	60mΩ @ V _{GS} = -10V	-4.4A		
-60V	80mΩ @ V _{GS} = -4.5V	-3.9A		

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- Backlighting
- Power-management functions
- DC-DC converters

Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

175°C P-CHANNEL ENHANCEMENT MODE MOSFET

https://www.diodes.com/quality/product-definitions/

 An automotive-compliant part is available under separate datasheet (<u>DMPH6051SSSQ</u>)

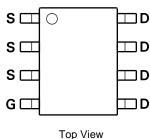
Mechanical Data

- Package: SO-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.076 grams (Approximate)

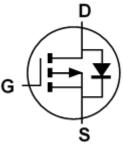


SO-8

Top View



Pin Configuration



Equivalent Circuit

Ordering Information (Note 4)

Orderable Part Number	Paakaga	Packing		
Orderable Part Nulliber	Fackage	Package Qty. Carrier		
DMPH6051SSS-13	SO-8	2500	Tape & Reel	

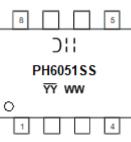
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



)'' = Manufacturer's Marking PH6051SS = Product Type Marking Code \overline{YY} WW = Date Code Marking \overline{YY} = Year (ex: 24 = 2024) WW = Week (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Value	Unit
Drain-Source Voltage		Vdss	-60	V
Gate-Source Voltage		Vgss	±20	V
Continuous Drain Current (Note 5) V _{GS} = -10V	T _A = +25°C T _A = +100°C	١D	-4.4 -3.1	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		IDM	-30	Α
Maximum Continuous Body Diode Forward Current (Note 5)		ls	-4.4	Α
Pulsed Source Current (10µs Pulse, Duty Cycle = 1%)		lsм	-30	А
Avalanche Current, L = 0.1mH		I _{AS}	-27.4	Α
Avalanche Energy, L = 0.1mH		Eas	37.5	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic			Value	Units
Total Power Dissipation (Note 6)		PD	2.1	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	73	°C/W
Total Power Dissipation (Note 5)		PD	2.4	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	63	°C/W
Operating and Storage Temperature Range		TJ, T _{STG}	-55 to +175	°C

Electrical Characteristics (T_A = +25°C, unless otherwise specified.)

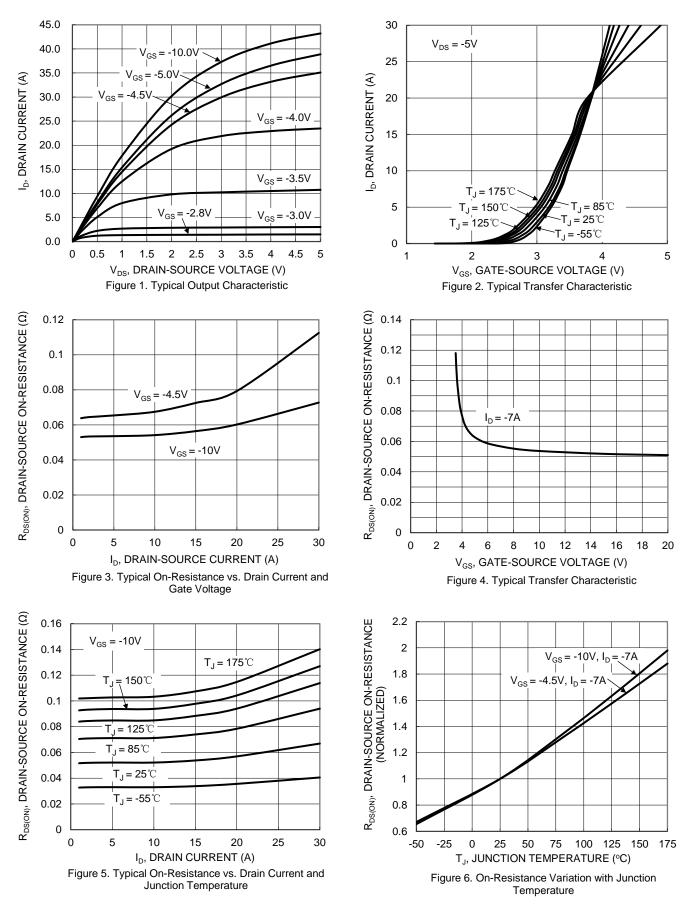
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)						•	
Drain-Source Breakdown Voltage	BV _{DSS}	-60			V	Vgs = 0V, ID = -250µA	
Zero Gate Voltage Drain Current	IDSS	—	_	-1	μA	$V_{DS} = -60V, V_{GS} = 0V$	
Gate-Source Leakage	lgss	_	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	Vgs(th)	-1	—	-3	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	
Static Drain-Source On-Resistance	Dearan	_	46	60	mΩ	V _{GS} = -10V, I _D = -7A	
Static Drain-Source On-Resistance	Rds(on)	—	58	80	11122	V _{GS} = -4.5V, I _D = -7A	
Diode Forward Voltage	Vsd	—	-0.8	-1.2	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	2079	_	pF		
Output Capacitance	Coss	_	95	_	pF	$V_{DS} = -30V, V_{GS} = 0V$ = f = 1MHz	
Reverse Transfer Capacitance	Crss	—	78	—	pF		
Gate Resistance	Rg	_	3.4	_	Ω	V_{DS} = 0V, V_{GS} = 0V, f = 1MHz	
Total Gate Charge (V _{GS} = -4.5V)	Qg	_	17	_	nC		
Total Gate Charge (V _{GS} = -10V)	Qg	_	36	_	nC		
Gate-Source Charge	Q _{gs}	_	5.7	_	nC	V _{DS} = -30V, I _D = -5A	
Gate-Drain Charge	Q _{gd}	_	6.7	_	nC		
Turn-On Delay Time	td(on)	_	6.2	_	ns		
Turn-On Rise Time	t _R	_	22	_	ns	V _{DD} = -30V, V _{GS} = -10V	
Turn-Off Delay Time	t _{D(OFF)}	—	39		ns	R _g = 3Ω, I _D = -5A	
Turn-Off Fall Time	tF		24.7		ns		
Body Diode Reverse Recovery Time	trr		24.5		ns		
Body Diode Reverse Recovery Charge	Qrr		23.4		nC	— I _F = -5A, di/dt = 100A/μs	

 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout. Notes:

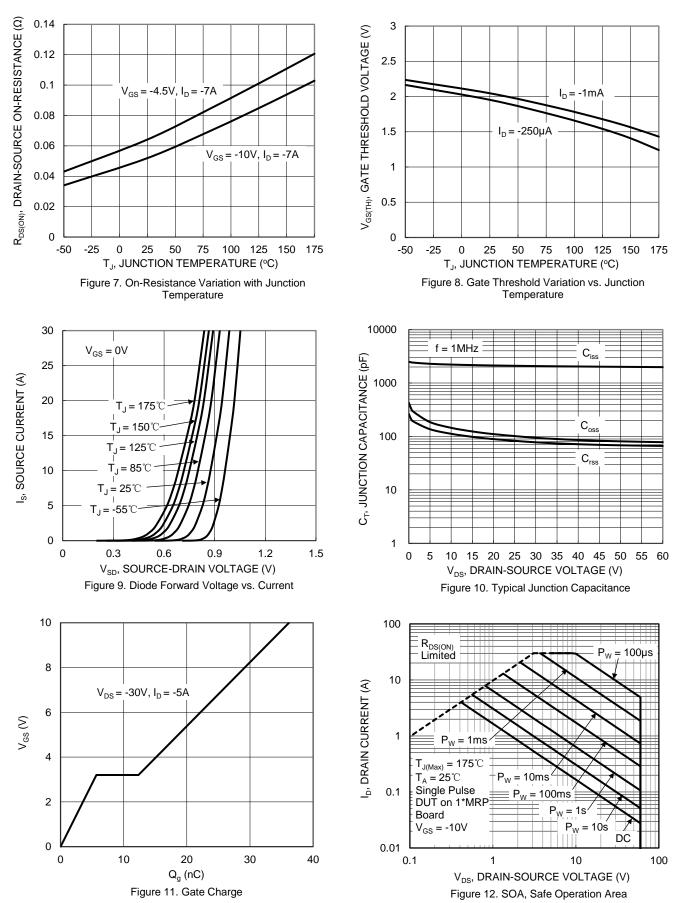
7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.



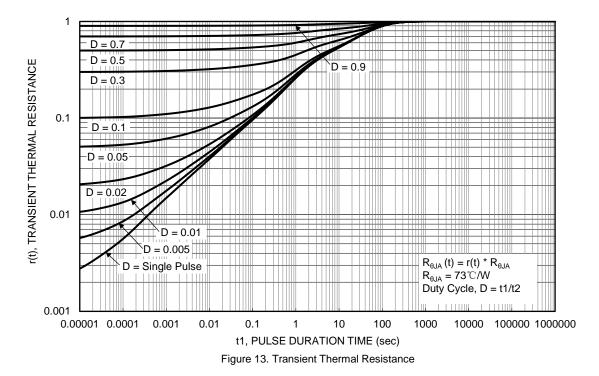






DMPH6051SSS Document number: DS46536 Rev. 1 - 2

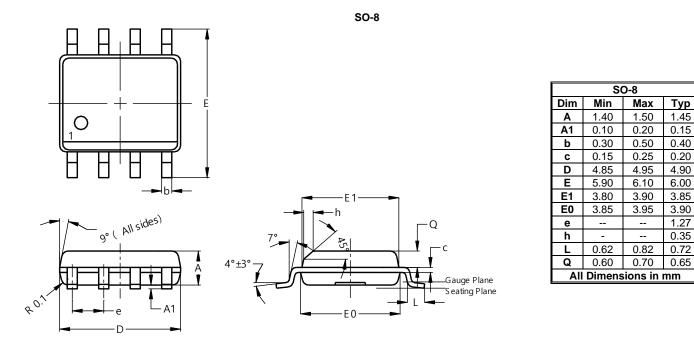






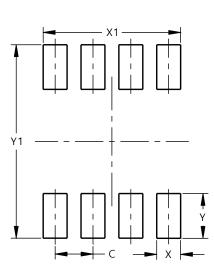
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SO-8

Dimensions	Value (in mm)
С	1.27
Х	0.802
X1	4.612
Y	1.505
Y1	6.50



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